

Contents lists available at ScienceDirect

Journal of Solid State Chemistry

journal homepage: <www.elsevier.com/locate/jssc>

First-principle studies of $Ca-X$ ($X=Si,Ge,Sn,Pb$) intermetallic compounds

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article info

Article history: Received 3 August 2009 Received in revised form 26 October 2009 Accepted 1 November 2009 Available online 10 November 2009

Keywords: Intermetallics Band structures Elastic properties Heats of formation First-principle calculations

1. Introduction

Due to their unique properties and potential technological applications in metallurgy, chemical engineering, aeronautics as well as astronautics, substantial recent efforts have been devoted to the search for intermetallic compounds [\[1–3\]](#page-7-0). Among these intermetallic compounds, Ca–X (X=Si, Ge, Sn, Pb) system intermetallic compounds have drawn considerable attention owing to their practical applications in thermoelectric and optoelectric materials and in the design of novel electronic devices [\[4,5\]](#page-7-0). Based on earlier results, phase diagrams of Ca–X systems have been investigated by Manfrinetti [\[6\],](#page-7-0) Palenzona [\[7,8\]](#page-7-0), Okamoto [\[9\]](#page-7-0) and Bruzzone [\[10\]](#page-7-0). According to these phase diagrams, there are 20 intermetallic compounds, namely Ca₂Si, Ca₅Si₃, CaSi, Ca₃Si₄, CaSi₂, Ca₂Ge, Ca₅Ge₃, Ca₇Ge₆, CaGe, CaGe₂, Ca₂Sn, Ca₅Sn₃, Ca₃₆Sn₂₃, Ca₇Sn₆, CaSn, CaSn₃, Ca₂Pb, Ca₅Pb₃, CaPb, and CaPb₃.

Among these 20 types of intermetallic compounds, $Ca₂Si$, Ca₂Ge, Ca₂Sn, and Ca₂Pb have been extensively investigated experimentally and theoretically due to their unique semiconductor properties [\[5–14\]](#page-7-0). For example, various aspects such as structural properties [\[5–10,13\]](#page-7-0), energy band structures [\[5\],](#page-7-0) electronic densities of states [\[5\]](#page-7-0), dielectric functions [\[5\],](#page-7-0) and heats of formation [\[11,12,14\]](#page-7-0) have been explored systematically. As a newly discovered compound $Ca₃Si₄$, its structural properties, energy band structures, transport properties and dielectric functions have been studied by Manfrinetti and Migas et al. It

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ABSTRACT

The structural properties, elastic properties, heats of formation, electronic structures, and densities of states of 20 intermetallic compounds in the Ca–X (X=Si, Ge, Sn, Pb) systems have been systematically investigated by using first-principle calculations. Our computational results indicated that with increasing atomic weight of X, the bulk modulus of Ca–X intermetallic compounds decreases gradually. It was also found that $Ca₃₆Sn₂₃$ and CaPb are mechanically unstable phases. Results on the electronic energy band and densities of states also indicated that $Ca₃Si₄$ is an indirect band gap semiconductor with a band gap of 0.598 eV, and Ca_2Si , Ca_2Ge , Ca_2Sn , and Ca_2Pb are direct band gap semiconductors with band gaps of 0.324, 0.265, 0.06, and 0.07 eV, respectively. In addition, it is found that the absolute values of heats of formation for all Ca–X intermetallics are larger than 30 kJ/mol atom.

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has been found that $Ca₃Si₄$ is an indirect band gap semiconductor with a band gap of 0.35 eV [\[4,6\]](#page-7-0). Moreover, it has been reported that $Ca₅Si₃$ and CaSi can emerge as promising candidates for hydrogen storage materials [\[15\].](#page-7-0) As for other Ca–X system intermetallic compounds, much attention has been focused on their heats of formation [\[16–18\]](#page-7-0), but systematical first-principle calculations are still lacking. In addition, their elastic properties and electronic structures have hardly been investigated in this context, despite their significant potential applications. Therefore, it is important to perform systematical studies on the Ca–X system intermetallic compounds. In this paper, the structural properties, elastic properties, mechanical stability, thermodynamic stability, heats of formation, electronic structures, and densities of states of the 20 Ca–X system intermetallic compounds have been studied by using first-principle calculations.

2. Computational method

Twenty types of Ca–X system intermetallic compounds have been investigated by using density functional theory (DFT) and plane-wave pseudopotential technique implemented in the CA-STEP package [\[19\]](#page-7-0). In this computational scheme, the ultrasoft pseudopotentials have been employed for the $3p^64s^2$, $3s^23p^2$, $3d^{10}4s^24p^2$, $4d^{10}5s^25p^2$, and $5d^{10}6s^26p^2$ atom configurations of Ca, Si, Ge, Sn, and Pb [\[20\].](#page-7-0) Exchange-correlation interaction was described by using the generalized gradient approximation with the Perdew–Burke–Ernzerh parameterization $[21]$. The **k** point separation in the Brillouin zone of the reciprocal space is 0.04 nm⁻¹, that is, $3 \times 5 \times 3$, $4 \times 4 \times 5$, $6 \times 6 \times 6$, $3 \times 3 \times 2$,

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^{0022-4596/\$ -} see front matter \circ 2009 Elsevier Inc. All rights reserved. doi:[10.1016/j.jssc.2009.11.007](dx.doi.org/10.1016/j.jssc.2009.11.007)

 $7 \times 7 \times 7$ for Ca₂Si, Ca₅Si₃, CaSi, Ca₃Si₄, CaSi₂; $3 \times 5 \times 3$, $4 \times 4 \times 5$, $3 \times 1 \times 3$, $6 \times 6 \times 6$, $7 \times 7 \times 2$ for Ca₂Ge, Ca₅Ge₃, Ca₇Ge₆, CaGe, CaGe₂; $3 \times 4 \times 2$, $3 \times 3 \times 3$, $2 \times 2 \times 1$, $3 \times 1 \times 2$, $5 \times 5 \times 5$, $4 \times 4 \times 4$ for Ca₂Sn, Ca₅Sn₃, Ca₃₆Sn₂₃, Ca₇Sn₆, CaSn, CaSn₃; $3 \times 5 \times 3$, $2 \times 2 \times 4$, $5 \times 5 \times 5$, $6 \times 6 \times 6$ for Ca₂Pb, Ca₅Pb₃, CaPb, CaPb₃, respectively. The kinetic cutoff energy for plane waves was determined as 400 eV.

To validate the performance of the present first-principle method, benchmark calculations have been performed for the CaPb₃ phase. The calculated lattice parameter of 4.970 Å agrees well with the experimental value of 4.900 Å [\[10\].](#page-7-0) Moreover, the calculated heat of formation for the CaPb₃ phase is -33.5 kJ/ mol atoms, which is consistent with experimental data of -35.0 kJ/mol atoms [\[22\].](#page-7-0) These results indicate that the computational scheme utilized in this work is credible.

3. Results and discussion

3.1. Structural properties

In this work, the initial crystal structures have been built on the basis of the experimental crystallographic data of the 20 types of Ca–X system intermetallic compounds [\[6–8,10,23–33\],](#page-7-0) and then the lattice parameters and internal coordinates of the 20 compounds were optimized by using first-principle calculations. The optimized lattice parameters and mass densities are summarized in Table 1 in comparison with the available experimental data and their corresponding crystal structures. It is clearly seen that all the lattice parameters obtained by using first-principle calculations are very close to the previous experimental values. These agreements of optimized lattice parameters and calculated mass densities with the experimental values provide an additional confirmation that the computational methodology utilized in this paper is suitable and reliable.

3.2. Elastic properties and mechanical stability

The elastic constants C_{ij} (GPa) and bulk moduli of the 20 Ca–X system intermetallic compounds have been calculated by using DFT calculations. The methodology of the calculation has been described by Nye [\[34\],](#page-7-0) Ashcroft and Mermin [\[35\]](#page-7-0). The elastic constants C_{ii} (GPa) were determined by applying small strains of order 0.003. Calculated results together with their previous theoretical values [\[5,18\]](#page-7-0) are shown in [Table 2](#page-2-0). Mechanical stability of the 20 compounds has been analyzed in terms of their elastic constants. For cubic crystals, the conditions for mechanical stability are given by [\[36\]](#page-7-0)

$$
C_{11} > 0, C_{44} > 0, C_{11} - C_{12} > 0, C_{11} + 2C_{12} > 0
$$
 (1)

Table 1

Calculated and experimental lattice parameters for Ca–X system intermetallic compounds.

As can be seen from Table 2, all the elastic constants of the cubic structures ($CaSn₃$ and $CaPb₃$) satisfy the above restrictions in Eq. (1), and this indicates that these cubic structures are all mechanically stable.

For tetragonal structures, the mechanical stability criteria can be expressed as follows [\[36\]:](#page-7-0)

$$
C_{11} > 0, C_{33} > 0, C_{44} > 0, C_{66} > 0, C_{11} - C_{12} > 0, C_{11} + C_{33}-2C_{13} > 0, 2C_{11} + C_{33} + 2C_{12} + 4C_{13} > 0
$$
\n(2)

Among the five tetragonal structures, that is, $Ca₅Si₃$, $Ca₅Ge₃$, $Ca₅Sn₃, Ca₃₆Sn₂₃, and Capb, the elastic constants of $Ca₅Si₃$, $Ca₅Ge₃$,$ and $Ca₅Sn₃$ are consistent with the above restrictions in Eq. (2), and these results demonstrate that they are mechanically stable. However, for the Ca₃₆Sn₂₃ compound, C₁₁=95 > 0, C₃₃=52.8 > 0, C_{44} = -122.7 < 0, C_{66} =30.9 > 0, C_{11} - C_{12} =77.1 > 0, C_{11} + C_{33} - $2C_{13}=218>0$, $2C_{11}+C_{33}+2C_{12}+4C_{13}=138.2>0$. This implies that the Ca₃₆Sn₂₃ compound does not satisfy the restriction of C_{44} > 0. Note also that for the CaPb compound, C_{11} =39.56 > 0, C_{33} = $57.31 > 0$, $C_{44} = 13.62 > 0$, $C_{66} = -11.13 < 0$, $C_{11} - C_{12} = 13.68 > 0$ C_{11} + C_{33} – 2 C_{13} =38.75, 2 C_{11} + C_{33} +2 C_{12} +4 C_{13} =304.4 > 0. The calculated elastic constant C_{66} is negative, violating the mechanical stability criteria in Eq. (2). Although optimized lattice parameters of $Ca_{36}Sn_{23}$ and CaPb compounds are very close to the experimental data, our calculations reveal that $Ca₃₆Sn₂₃$ and $CaPb$ structures are mechanically unstable. There are three possible reasons for this: first, existing stress has not been considered in

Table 2

Calculated elastic properties compared to other theoretical values for the single crystalline Ca–X system intermetallic compounds.

System	Phase	C_{11}	C_{12}	C_{13}	C_{22}	C_{23}	C_{33}	C_{44}	C_{55}	C_{66}	K
$Ca-Si$	Ca ₂ Si	82.1	19.4	16.9	74.9	31.6	69.1	26.9	18.1	32.2	40.1
	Ca ₂ Si										46.0 [5]
	Ca ₂ Si										40.0 $[5]$
	Ca ₅ Si ₃	79.6	20.9	27.0			56.4	31.9		39.6	40.0
	CaSi	99.0	26.8	25.7	101.7	26.8	125.6	36.9	50.0	34.5	53.4
	Ca ₃ Si ₄	117.8	31.1	23.6			121.7	38.1			57.1
	CaSi ₂	133.9	47.1	29.9			92.6	43.2			60.7
$Ca-Ge$	Ca ₂ Ge	67.1	20.7	23.5	67.5	27.2	67.4	23.6	14.7	31.5	38.3
	Ca ₅ Ge ₃	74.4	19.9	24.1			52.4	28.5		39.3	36.8
	Ca ₇ Ge ₆	75.1	24.8	26.5	72.4	28.7	72.2	34.8	28.6	31.8	42.2
	CaGe	92.8	23.0	23.9	90.2	22.8	107.7	33.3	44.6	29.2	47.5
	CaGe ₂	87.4	32.3	31.9			72.6	36.4			48.4
$Ca-Sn$	Ca ₂ Sn	36.2	27.7	11.3	58.3	33.2	42.5	14.7	15.0	26.4	24.0
	Ca ₂ Sn										29.8 [18]
	Ca ₅ Sn ₃	64.9	22.2	20.7			43.6	24.9		34.7	32.2
	Ca ₅ Sn ₃										32.6 [18]
	$Ca_{36}Sn_{23}$	95.0	17.9	-35.1			52.8	-122.7		30.9	10
	Ca ₇ Sn ₆	56.7	23.5	31.9	61.0	31.6	45.0	21.9	24.9	12.3	37.2
	CaSn	76.4	11.3	22.3	82.5	22.3	69.0	20.6	33.3	19.9	37.7
	CaSn										39.0 [18]
	CaSn ₃	74.0	32.8					4.6			46.5
	CaSn ₃										45.9 [18]
$Ca-Pb$	Ca ₂ Pb	31.5	22.3	18.5	54.4	21.5	53.8	16.5	15.6	24.2	27.1
	Ca ₅ Pb ₃	64.5	17.5	11.4			46.5	14.5			27.5
	CaPb	31.6	25.9	29.1			57.3	13.6		-11.1	32.3
	CaPb ₃	50.2	29.5					20.2			36.4

 C_{ii} , elastic stiffness (in GPa); K, bulk modulus (in GPa).

Table 3

Polycrystalline bulk modulus, shear modulus, Young's modulus (GPa), Poisson's ratio for Ca–X system intermetallic compounds deduced by Voigt, Reuss, and Hill (VRH) approximations.

 K , bulk modulus (in GPa); G , shear modulus (in GPa); E , Young's modulus (in GPa); v, Poisson's ratio.

the experimental measurement; second, inasmuch as the nearest neighbor distance between Sn–Sn, Sn–Ca and Ca–Ca are 3.023, 3.042 and 3.169 Å [\[8\],](#page-7-0) respectively, the nature of the interactions between Sn–Sn, Sn–Ca and Ca–Ca may be the reason for mechanical unstability of $Ca_{36}Sn_{23}$; third, the magnetism of $Ca₃₆Sn₂₃$ and CaPb may affect the elastic constants. To clarify further the mechanical stability of $Ca_{36}Sn_{23}$ and CaPb, more attention should be paid to this issue.

For hexagonal structures, the mechanical stability restrictions can be expressed as follows [\[37,38\]:](#page-7-0)

$$
C_{11} > 0, C_{44} > 0, C_{11} - C_{12} > 0, (C_{11} + C_{12})C_{33} - 2C_{13}^2 > 0
$$
 (3)

As shown in [Table 2,](#page-2-0) the elastic constants of the hexagonal structures ($Ca₃Si₄$, $CaSi₂$, $CaGe₂$, and $Ca₅Pb₃$) can comply with all these stability criteria in (3), and this indicates that all of these structures are mechanically stable.

The mechanical stability criteria orthorhombic structures are as follows [\[39\]:](#page-7-0)

$$
C_{11} > 0, C_{22} > 0, C_{33} > 0, C_{44} > 0, C_{55} > 0, C_{66} > 0, C_{11} + C_{22} -2C_{12} > 0, C_{11} + C_{33} -2C_{13} > 0, C_{22} + C_{33} -2C_{23} > 0, C_{11} + C_{22} + C_{33} + 2C_{12} + 2C_{13} + 2C_{23} > 0.
$$
\n(4)

Based on the elastic constants of orthorhombic structures (Ca₂Si, CaSi, Ca₂Ge, Ca₇Ge₆, CaGe, Ca₂Sn, Ca₇Sn₆, CaSn, and Ca₂Pb)

Fig. 1. Calculated (a) bulk moduli and (b) shear moduli of Ca–X system intermetallic compounds.

in [Table 2,](#page-2-0) all the orthorhombic structures compounds considered in this paper are mechanically stable.

To further understand the mechanical properties, we have deduced the polycrystalline bulk modulus (K) , shear modulus (G) , Young's modulus (E) , and Poisson's ratio (v) using Voigt, Reuss, and Hill (VRH) approximations based on their single-crystal elastic constants [\[40\],](#page-7-0) and the results are shown in [Table 3.](#page-2-0) Fig. 1(a) shows the relationship between bulk modulus and concentration of X. It is clearly shown that the bulk modulus increases nearly monotonously with the increasing concentration of X (in atom%), except that of $Ca_{36}Sn_{23}$. For the $Ca_{36}Sn_{23}$

Table 4

Calculated and experimental heats of formation for Ca–X system intermetallic compounds.

System	Phase	Heat of formation (kJ/mol atoms)	Reference	
Ca-Si	Ca ₂ Si	-44.8	This work	
		-56.1	[11]	
		-56.1	[44]	
		-47.1	$[17]$	
	Ca ₅ Si ₃	-47.2	This work	
		-55.3	[11]	
		-55.3	[44]	
		-49.2	$[17]$	
	CaSi	-52.4	This work	
		-48.9	[11]	
		-49.6	$[44]$	
		-43.5 -45.8	$[17]$ This work	
	Ca ₃ Si ₄	-46.0	[11]	
		-40.6	$[44]$	
		-40.4	$[17]$	
	CaSi ₂	-37.1	This work	
		-37.8	[11]	
		-37.8	$[44]$	
		-31.2	$[17]$	
Ca-Ge	Ca ₂ Ge	-58.9	This work	
	Ca ₅ Ge ₃	-60.4	This work	
	Ca ₇ Ge ₆	-61.4	This work	
	CaGe	-64.3	This work	
	CaGe ₂	-46.8	This work	
$Ca-Sn$	Ca ₂ Sn	-63.4	This work	
		-57.8	$[45]$	
		-66.4	$[16]$	
		-83.1	[12]	
	Ca ₅ Sn ₃	-63.1 -63.6	This work [45]	
		-65.8	[16]	
		-86.6	[12]	
	$Ca_{36}Sn_{23}$	-63.5	This work	
		-65.4	$[45]$	
		-66.3	[16]	
		-85.8	$[12]$	
	Ca ₇ Sn ₆	-62.6	This work	
		-71.4	$[45]$	
		-65.1	$[16]$	
		-75.7	$[12]$	
	CaSn	-63.0	This work	
		-72.7	[45]	
		-66.3	[16]	
	CaSn ₃	-70.2 -42.0	$[12]$ This work	
		-47.8	[45]	
		-40.9	$[16]$	
		-37.7	$[12]$	
$Ca-Pb$	Ca ₂ Pb	-56.4	This work	
		-59.0	[22]	
	Ca ₅ Pb ₃	-52.8	This work	
		-56.0	$[22]$	
	CaPb	-51.9	This work	
		-57.0	[22]	
	CaPb ₃	-36.8	This work	
		-35.0	$[22]$	

compound, the calculated bulk modulus is 15.4 GPa, which is much lower than that of other Ca–X system intermetallic compounds. The bulk modulus of Ca–Si system compounds is larger than that of Ca–Ge, Ca–Sn, and Ca–Pb system compounds. This can be explained by the calculated high bulk modulus of 89 GPa for pure Si. With increasing atomic weight of X, all the bulk moduli of Ca–X system intermetallic compounds decrease gradually. These results are in agreement with the results for the Mg–X ($X = Si$, Ge, Sn) compounds calculated by Ganeshan et al. [\[41\]](#page-7-0). Now, since the valence electron densities of Si, Ge, Sn, and Pb are the same, the decrease in bulk modulus is due to the increase in X atomic radius with the increasing atom weight of X. In addition, the relationship between shear modulus and the concentration of X has been plotted in [Fig. 1\(](#page-3-0)b). With the increase in the concentration of X c (in atom%), the shear modulus for Ca–Si system compounds increases monotonously. The tendency indicates that the hardness of Ca– Si system compounds increases with the increasing of X concentration c. As for Ca–Ge, Ca–Sn, and Ca–Pb system compounds, the shear modulus changes disorderly. The shear modulus of Ca $_{36}$ Sn $_{23}$ compound is -23.2 GPa, which is also much lower than that of other Ca–Sn system compounds. For all the 20 Ca–X system intermetallic compounds, it is found that the hardness of CaPb compound is the smallest and $CaSi₂$ compound is the largest.

In order to further analyze the mechanical properties of the 20 Ca–X system intermetallic compounds, brittleness and ductility properties have also been studied by using the shear modulus to bulk modulus (G/K) ratio and Poisson's ratio. According to Pugh [\[42\]](#page-7-0), if G/K ratio is larger than 0.57, the material behaves in a brittle manner, otherwise the material behaves in a ductile manner. For our computational scheme, the values of G/K are

shown in [Table 3](#page-2-0). In terms of the G/K values, $Ca₂Sn$, $Ca₇Sn₆$, $CaSn₃$, $Ca₂Pb$, CaPb, and CaPb₃ are ductile materials, and the ductility of these compounds ranks as follows: $CaSn₃ > Ca₇Sn₆ > Ca₂Sn$, $CaPb > CaPb₃ > Ca₂Pb$. All the Ca–Si and Ca–Ge system compounds are brittle materials, and the brittleness of these compounds ranks as follows: $Ca₃Si₄ > CaSi₃ > CaSi₂ > Ca₂$ Si, Ca_7Ge_6 > $CaGe_2Ca_5Ge_3$ > $CaGe_2$ > Ca_2Ge . For other Ca–Sn system compounds, the brittleness of these compounds ranks as follows: $Ca_{36}Sn_{23} > Ca_5Sn_3 > CaSn$. According to Frantsevich et al. [\[43\]](#page-7-0). Poisson's ratio can also be used to distinguish the brittleness from ductility in metal and intermetallic materials. Metals having a Poisson's ratio around 1/3 are ductile, whereas metals having a Poisson's ratio less than 1/3 are inferred as being brittle. On the basis of the Poisson's ratio shown in [Table 3,](#page-2-0) the brittleness and ductility properties of the 20 compounds determined by Poisson's ratio ν criterion are in good agreement with the results estimated by the G/K ratio.

3.3. Thermodynamic stability and heats of formation

In order to investigate further physical properties of our intermetallic compounds, heats of formation of all the 20 compounds have been calculated by using the following formula:

$$
E_{\text{form}}^{\text{Ca}_{m}X_{n}} = E_{\text{tot}}^{\text{Ca}_{m}X_{n}} - (mE_{\text{solid}}^{\text{Ca}} + nE_{\text{solid}}^{X})/(m+n),
$$
\n(5)

where $E_{\text{tot}}^{C_{\text{d}_{m}}X_{n}}$ represents the total energy of a $C_{\text{d}_{m}}X_{n}$ primitive cell that includes m Ca atoms and n X atoms with equilibrium lattice parameters, $E_{\text{solid}}^{\text{Ca}}$ is the total energy of a Ca atom, and $E_{\text{solid}}^{\text{X}}$ is the total energy of an X (X=Si, Ge, Sn, Pb) atom.

The calculated heats of formation of the 20 compounds together with their available experimental and theoretical data

Fig. 2. Calculated heats of formation compared to experimental and theoretical values for Ca–X system intermetallic compounds.

[\[11,12,16,17,22,44,45\]](#page-7-0) are summarized in [Table 4](#page-3-0). In order to clearly see the comparison between calculated results and previous data, these results have also been depicted in [Fig. 2.](#page-4-0) As we can see from [Table 4](#page-3-0) and [Fig. 2](#page-4-0), all the Ca–X system intermetallics values of heats of formation are in a very good agreement with the previous experimental and theoretical data.

Fig. 3. The electronic energy band structures and densities of states of Ca-X system intermetallic compounds. Zero of the energy corresponds to the Fermi energy.

In addition, all the absolute values of heats of formation are larger than 30 kJ/mol atoms, and these results indicate a very strong chemical interaction between Ca–Si, Ca–Ge, Ca–Sn, and Ca–Pb.

Judging from the obtained negative heats of formation, we can conclude that all the Ca–X system intermetallic compounds are thermodynamically stable.

3.4. Electronic energy band structures and densities of states

The electronic energy band structures and densities of states of the 20 Ca–X system intermetallic compounds considered in this work have also been calculated, and the results are shown in [Fig. 3](#page-5-0). The zero energy represents the Fermi level. As shown in [Fig. 3,](#page-5-0) all the valence band maximum and the conduction band minimum of Ca₂Si, Ca₂Ge, Ca₂Sn, and Ca₂Pb are located at G point. The band gaps for Ca₂Si, Ca₂Ge, Ca₂Sn and Ca₂Pb are 0.324, 0.265, 0.06 and 0.07 eV, respectively. This indicates that all the $Ca₂X$ intermetallic compounds are direct band gap semiconductors. Moreover, these results are in accordance with other theoretical calculations carried out by Migas and Miglio [5]. As for $Ca₃Si₄$ compounds, the top of the valence band is localized at $0.7 \times K$ –G and the lowest conduction band minimum is situated at $0.5 \times H-$ K. The band gap for $Ca₃Si₄$ compounds is 0.598 eV. Therefore, $Ca₃Si₄$ is an indirect band gap semiconductor, and the result is in a fairly good agreement with the discovery reported in Ref. [4]. As for other intermetallics considered in the 20 compounds, their valence band overlaps the conduction band at the Fermi surface in the diagrams. This indicates that all of them are conductors. Electrical properties of the 20 Ca–X system intermetallic compounds are also further elucidated by their corresponding densities of states.

4. Conclusions

We have investigated the structural properties, elastic properties, heats of formation, electronic structures, and densities of states of the 20 types of $Ca-X$ ($X=Si$, Ge , Sn , Pb) system intermetallic compounds using density functional theory. It is found that all bulk moduli of Ca–X system intermetallic compounds decrease with the increasing of X atomic weight. Moreover, most of the 20 intermetallics considered in this work are mechanically stable except those of $Ca_{36}Sn_{23}$ and CaPb. The analysis on the electronic structures of the 20 compounds shows that $Ca₃Si₄$ is an indirect band gap semiconductor with a band gap of 0.598 eV, and Ca₂Si, Ca₂Ge, Ca₂Sn, and Ca₂Pb are direct band gap semiconductors with band gaps of 0.324, 0.265, 0.06, and 0.07 eV, respectively. In addition, our calculations also revealed that the absolute values of heats of formation of all the Ca–X intermetallics are larger than that of 30 kJ/mol atom, indicating a very strong chemical interaction among Ca–Si, Ca–Ge, Ca–Sn and Ca–Pb.

Acknowledgments

This work was supported by the National Natural Science Foundation of China (Grant nos. 50772018, 50402025) and the Program for New Century Excellent Talents in Universities of China (NCET-07-0139). R.M. acknowledges the support from the NSERC and CRC programs. B.W. acknowledges computational support from Prof. J.J. Zhao of Dalian University of Technology of China.

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